

	Type	Hits	Search Text
1	BRS	76006	((lower or bottom) near2 electrode\$3)
2	BRS	30577	(insulat\$6 or ILD) near8 (SiN or "silicon nitride" or PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)
3	BRS	4474409	open\$6 or gap\$3 or trench\$6
4	BRS	19	"source pad electrode"
5	BRS	265	((lower or bottom) near2 electrode\$3)) same ((insulat\$6 or ILD) near8 (SiN or "silicon nitride" or PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)) same (open\$6 or gap\$3 or trench\$6)
6	BRS	424	(insulat\$6 or ILD) near8 (SiN or "silicon nitride") near8 (PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)
7	BRS	6	((lower or bottom) near2 electrode\$3)) same ((insulat\$6 or ILD) near8 (SiN or "silicon nitride") near8 (PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate))
8	BRS	9535	damascene
9	BRS	29	((insulat\$6 or ILD) near8 (SiN or "silicon nitride") near8 (PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)) and damascene
10	BRS	64632	MOSFET or "metal oxide semiconductor field effect transistor"
11	BRS	17	TiNiAg
12	BRS	306	((insulat\$6 or ILD) near8 (SiN or "silicon nitride" or PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)) same damascene

	DBs	Time Stamp
1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:22
2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:33
3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:27
4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:29
5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:30
6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:34
7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:35
8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:46
9	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:38
10	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:38
11	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:00
12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:45

	Type	Hits	Search Text
13	BRS	27	((insulat\$6 or ILD) near8 (SiN or "silicon nitride" or PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)) same damascene) and (MOSFET or "metal oxide semiconductor field effect transistor")
14	BRS	29	((insulat\$6 or ILD) near8 (SiN or "silicon nitride") near8 (PSG or "phospho silicate glass" or phospho-silicate or phosphosilicate)) and damascene
15	BRS	89265	(up or top or upper) near2 electrode\$3
16	BRS	116	((lower or bottom) near2 electrode\$3) same ((up or top or upper) near2 electrode\$3) same damascene
17	BRS	28	((lower or bottom) near2 electrode\$3) same ((up or top or upper) near2 electrode\$3) same damascene) and @ad<20001226
18	BRS	17	TiNiAg
19	BRS	413	bond\$6 adj pad adj electrode\$4
20	BRS	53980	lift-off or (lift near2 off) or (lifted near2 off) or (lifting near2 off)
21	BRS	16	(bond\$6 adj pad adj electrode\$4) and (lift-off or (lift near2 off) or (lifted near2 off) or (lifting near2 off))
22	BRS	378	438/615
23	BRS	1294	257/762
24	BRS	2372	257/784
25	BRS	1797	257/763
26	BRS	789	257/766

	DBs	Time Stamp
13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:42
14	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:46
15	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:47
16	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:47
17	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 09:48
18	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:01
19	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:01
20	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:02
21	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:02
22	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:03
23	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:03
24	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:03
25	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:03
26	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:03

	Type	Hits	Search Text
27	BRS	640	257/772
28	BRS	1554	257/779

	DBs	Time Stamp
27	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:04
28	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/03/05 10:04